# **WDJ26HXX LOW DROPOUT LINEAR REGULATOR**

#### **GENERAL DESCRIPTION**

WDJ26HXX series are a set of Low Dropout Linear Regulator ICs implemented in CMOS technology. They can withstand voltage 48V. And they are available with low voltage drop and low quiescent current, widely used in audio, video and communication appliances.

#### FEATURES

- Low Power Consumption
- Low Voltage Drop
- Low Temperature Coefficient
- Withstanding Voltage 48V
- Quiescent Current 2.0µA
- Output Voltage Accuracy: tolerance  $\pm 1\%$
- Output short circuit protection
- Temperature exceeds 120 ° C output current decreases

## **TYPICAL APPLICATIONS**

- Battery-powered Equipments
- Communication Equipments
- Audio/Video Equipments
- Smart Battery Packs
- Smoke Detectors
- Power Meter, Water Meter, Smart Meter

## **PIN CONFIGURATION**



# **ORDERING INFORMATION**



#### **PIN DESCRIPTION**

PIN	No.	NT				
SOT-89	SOT23-3	Name	Functions Description			
1	1	GND	ground			
2	2	$V_{IN}$	input			
3	3	Vout	output			

# FUNCTIONAL BLOCK DIAGRAM



#### **ABSOLUTE MAXIMUM RATINGS**

Description	Symbol	Value range	Unit
Limit Power Voltage	V <sub>IN</sub>	$-0.3 \sim +52$	V
Storage Temperature Range	T <sub>STG</sub>	$-50 \sim +125$	°C
Operating Free-air Temperature Range	T <sub>A</sub>	$-40 \sim +85$	°C
Maximum Junction Temperature	TJ	150	Ĉ

**Note :** Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

When the junction temperature reaches 150°C, the system can work, but the IC has over-temperature protection. the junction temperature exceeds 120°C, the output current decreases.

#### HEAT DISSIPATION

Description	Symbol	Package	Value range	Unit
Thermal resistance	$\theta_{JA}$	SOT-89	200	°C/W
	- 57 1	SOT23-3	500	°C/W
Power dissipation	wer dissipation Pw		500	mW
Ĩ		SOT23-3	200	mW

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Output Voltage	Vout	$V_{IN}=V_{OUT}+2.0V,$ $I_{OUT}=10mA$	2.97	3.0	3.03	V
Output Current	I <sub>OUT</sub>	$V_{IN}=V_{OUT}+2.0V$	—	250	-	mA
Load Regulation	$\Delta V_{OUT}$	$\begin{array}{l} V_{IN} = V_{OUT} + 2.0V \\ 1mA \leq I_{OUT} \leq 200mA \end{array}$		15	75	mV
Voltage Drop	V <sub>DIF</sub>	Iout=100mA, $\triangle V_{OUT}=2\%$		550	_	mV
Quiescent Current	I <sub>SS</sub>	No Load	_	2.0	3.0	μΑ
Line Regulation	$\frac{\bigtriangleup V_{\text{OUT}}/V_{\text{OUT}}*}{\bigtriangleup V_{\text{IN}}}$	$V_{OUT}$ +1.0V $\leq$ V <sub>IN</sub> $\leq$ 48V, I <sub>OUT</sub> =1mA			0.2	%/V
Input Voltage	V <sub>IN</sub>			_	48	V
Temperature Coefficient	$\begin{array}{c} \bigtriangleup V_{OUT} / \\ \bigtriangleup T_A * V_{OUT} \end{array}$	$V_{IN} = V_{OUT} + 2.0V,$ $I_{OUT} = 1 \text{mA},$ $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$		65	—	ppm/°C

## **DC CHARACTERISTICS** (unless otherwise noted $T_A = +25^{\circ}C$ ) **WDJ26H30**

#### Note :

When  $V_{IN}=V_{OUT}+2.0V$ , as the output voltage declined 2%, the  $V_{DIF}=V_{IN}-V_{OUT}$ .

The input withstand voltage value of 48V does not mean that the circuit can work normally under a 48V power supply voltage. When the machine is turned on or off, the voltage pulse generated on the 48V power supply may Far greater than 48V, causing permanent damage to the chip.

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Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Output Voltage	Vout	$V_{IN}=V_{OUT}+2.0V,$ $I_{OUT}=10mA$	3.267	3.30	3.333	V
Output Current	I <sub>OUT</sub>	V <sub>IN</sub> =V <sub>OUT</sub> +2.0V		250	_	mA
Load Regulation	$\Delta V_{OUT}$	$\begin{array}{l} V_{IN} = V_{OUT} + 2.0V \\ 1mA \leqslant I_{OUT} \leqslant 200mA \end{array}$		15	75	mV
Voltage Drop	V <sub>DIF</sub>	I <sub>OUT</sub> =100mA , $\triangle V_{OUT}$ =2%		550	_	mV
Quiescent Current	I <sub>SS</sub>	No Load	—	2.0	3.0	μΑ
Line Regulation	$\frac{\bigtriangleup V_{\text{OUT}}}{\bigtriangleup V_{\text{IN}}} *$	$V_{OUT}$ +1.0V $\leq$ V <sub>IN</sub> $\leq$ 48V, $I_{OUT}$ =1mA			0.2	%/V
Input Voltage	V <sub>IN</sub>				48	V
Temperature Coefficient	$\begin{array}{c} \bigtriangleup V_{OUT} / \\ \bigtriangleup T_A * V_{OUT} \end{array}$	$V_{IN} = V_{OUT} + 2.0V,$ $I_{OUT} = 1 \text{mA},$ $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$		65		ppm/°C

#### WDJ26H33

#### Note :

When  $V_{IN}=V_{OUT}+2.0V$ , as the output voltage declined 2%, the  $V_{DIF}=V_{IN}-V_{OUT}$ .

The input withstand voltage value of 48V does not mean that the circuit can work normally under a 48V power supply voltage. When the machine is turned on or off, the voltage pulse generated on the 48V power supply may Far greater than 48V, causing permanent damage to the chip.

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Output Voltage	Vout	$V_{IN}=V_{OUT}+2.0V,$ $I_{OUT}=10mA$	4.95	5.0	5.05	V
Output Current	I <sub>OUT</sub>	$V_{IN}=V_{OUT}+2.0V$		250	—	mA
Load Regulation	$\Delta V_{OUT}$	$\begin{array}{l} V_{IN} = V_{OUT} + 2.0V \\ 1mA \leq I_{OUT} \leq 200mA \end{array}$		15	72	mV
Voltage Drop	V <sub>DIF</sub>	I <sub>OUT</sub> =100mA , $\triangle V_{OUT}$ =2%		550	_	mV
Quiescent Current	I <sub>SS</sub>	No Load	_	2.0	3.0	μΑ
Line Regulation	$\frac{\bigtriangleup V_{\text{OUT}}/V_{\text{OUT}}*}{\bigtriangleup V_{\text{IN}}}$	$V_{OUT}$ +1.0V $\leq$ V <sub>IN</sub> $\leq$ 48V, I <sub>OUT</sub> =1mA		_	0.2	%/V
Input Voltage	$V_{IN}$				48	V
Temperature Coefficient	$\begin{array}{c} \bigtriangleup V_{OUT} / \\ \bigtriangleup T_A * V_{OUT} \end{array}$	$V_{IN} = V_{OUT} + 2.0V,$ $I_{OUT} = 1 \text{mA},$ $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$		65		ppm/°C

#### WDJ26H50

#### Note :

When  $V_{IN}=V_{OUT}+2.0V$ , as the output voltage declined 2%, the  $V_{DIF}=V_{IN}-V_{OUT}$ .

The input withstand voltage value of 48V does not mean that the circuit can work normally under a 48V power supply voltage. When the machine is turned on or off, the voltage pulse generated on the 48V power supply may Far greater than 48V, causing permanent damage to the chip.

### DTYPICAL PERFORMANCE CHARACTERISTIC

 $V_{IN} = 5.3V$ ,  $V_{OUT} = 3.3V$ , C1 = C2 = 10uF,  $T_A = 25^{\circ}C$ 



#### **APPLICATION DESCRIPTION**

The error amplifier compares the input voltage of the divider resistor composed of feedback resistors Rs and Rf with the reference voltage vref, and provides the necessary gate voltage to the output transistor through this error amplifier, so that the output voltage is not affected by input voltage or temperature changes and remains constant.



- 1. When applying, try to connect the capacitors close to the VIN and VOUT pins.
- 2. The circuit uses a phase compensation circuit and uses the ESR of the output capacitor for compensation. Therefore, a capacitor larger than  $2.2\mu$ F must be connected to the output ground. Tantalum capacitors are recommended.
- 3.Pay attention to the input and output voltage and load current conditions to prevent the power consumption inside the IC from exceeding the maximum power consumption allowed by the package.

## **TYPICAL APPLICATION CIRCUIT**



### **PACKAGE INFORMATION**





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